NSN 5962-01-424-7235

Memory Microcircuit - Page 1 of 1



View Online at https://aerobasegroup.com/nsn/5962-01-424-7235

Operating Tempurature Range:
-55.0/+125.0 degrees celsius
Storage Tempurature Range:
-65.0/+150.0 degrees celsius
Features Provided:
Beam lead chip and electrostatic sensitive
Inclosure Material:
Ceramic
Inclosure Configuration:
Dual-in-line
Output Logic Form:
Complementary-metal oxide-semiconductor logic
Input Circuit Pattern:
16 input
Terminal Surface Treatment:
Solder
Voltage Rating And Type Per Characteristic:
7.0 volts power source
7.0 volts power source Memory Device Type:
Memory Device Type:
Memory Device Type: Pal
Memory Device Type: Pal Terminal Type And Quantity:
Memory Device Type: Pal Terminal Type And Quantity: 20 printed circuit
Memory Device Type: Pal Terminal Type And Quantity: 20 printed circuit Shelf Life:
Memory Device Type: Pal Terminal Type And Quantity: 20 printed circuit Shelf Life: N/a
Memory Device Type: Pal Terminal Type And Quantity: 20 printed circuit Shelf Life: N/a
Memory Device Type: Pal Terminal Type And Quantity: 20 printed circuit Shelf Life: N/a Unit Of Measure:
Memory Device Type: Pal Terminal Type And Quantity: 20 printed circuit Shelf Life: N/a Unit Of Measure: Demilitarization:
Memory Device Type: Pal Terminal Type And Quantity: 20 printed circuit Shelf Life: N/a Unit Of Measure: Demilitarization: Yes - demil/mli
Memory Device Type: Pal Terminal Type And Quantity: 20 printed circuit Shelf Life: N/a Unit Of Measure: Demilitarization: Yes - demil/mli Fiig:
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